Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-026-1254

Inclosure Material:

Metal

Overall Length:

Between 0.115 inches and 0.150 inches

Overall Diameter:

Between 0.209 inches and 0.230 inches

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-52

Component Name And Quantity:

2 transistor

Mounting Method:

Terminal

Semiconductor Material:

Silicon all transistor

Voltage Rating In Volts Per Characteristic:

45.0 collector to base voltage/static/emitter open all transistor and 45.0 collector to emitter voltage/static/base open all transistor and 6.0

emitter to base voltage, static, collector open all transistor

Current Rating Per Characteristic:

20.00 milliamperes source cutoff current all transistor

Special Features:

Matched for high gain and base-emitter voltage; all transistor junction pattern arrangement: pnp

Terminal Type And Quantity:

6 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

A110a0